

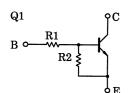
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process) Silicon PNP Epitaxial Type (PCT Process)

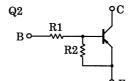
RN4981

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Includeing two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

Equivalent Circuit and Bias Resister Values

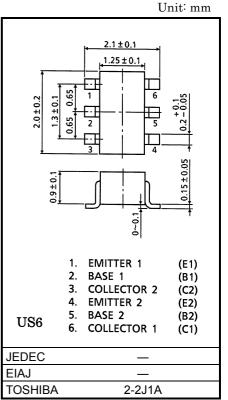




R1: 4.7kΩ R2: 4.7kΩ (Q1, Q2 Common)

Q1 Maximum Ratings (Ta = 25°C)

-			
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V _{EBO}	10	V
Collector current	Ic	100	mA



Weight: 6.8mg

Q2 Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-50	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-10	V
Collector current	IC	-100	mA

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Q1, Q2 Common Maximum Ratings (Ta = 25°C)

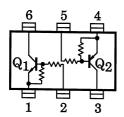
Characteristic	Symbol	Rating	Unit
Collector power dissipation	P _C *	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

^{*} Total rating

Marking



Equivalent Circuit (Top View)



Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
Collector cut-on current	I _{CEO}	_	V _{CE} = 50V, I _B = 0	_	_	500	
Emitter cut-off current	I _{EBO}	_	V _{EB} = 10V, I _C = 0	0.82	_	1.52	mA
DC current gain	h _{FE}	_	V _{CE} = 5V, I _C = 10mA	30	_	_	_
Collector-emitter saturation voltage	V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
Input voltage (ON)	V _{I (ON)}	_	V _{CE} = 0.2V, I _C = 5mA	1.1	_	2.0	V
Input voltage (OFF)	V _{I (OFF)}	_	V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	V
Transition frequency	f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1 MHz	_	3	6	pF

Q2 Electrical Characteristics (Ta = 25°C)

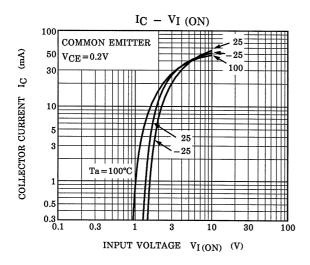
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	V _{CB} = -50V, I _E = 0	_	_	-100	nA
	I _{CEO}	_	V _{CE} = -50V, I _B = 0	_	_	-500	
Emitter cut-off current	I _{EBO}	_	$V_{EB} = -10V, I_C = 0$	-0.82	_	-1.52	mA
DC current gain	h _{FE}	_	V _{CE} = -5V, I _C = -10mA	30	_	_	_
Collector-emitter saturation voltage	V _{CE} (sat)	_	$I_C = -5mA$, $I_B = -0.25mA$	_	-0.1	-0.3	V
Input voltage (ON)	V _{I (ON)}	_	$V_{CE} = -0.2V$, $I_{C} = -5mA$	-1.1	_	-2.0	V
Input voltage (OFF)	V _{I (OFF)}	_	$V_{CE} = -5V, I_{C} = -0.1mA$	-1.0	_	-1.5	V
Transition frequency	f _T	_	V _{CE} = −10V, I _C = −5mA	_	200	_	MHz
Collector output capacitance	C _{ob}	_	V _{CB} = −10V, I _E = 0, f = 1MHz	_	3	6	pF

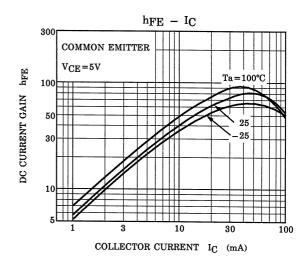
Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

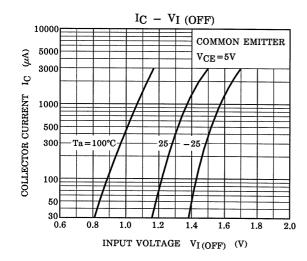
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input resistor	R1	_	_	3.29	4.7	6.11	kΩ
Resistor ratio	R1/R2	_	ı	0.9	1.0	1.1	_

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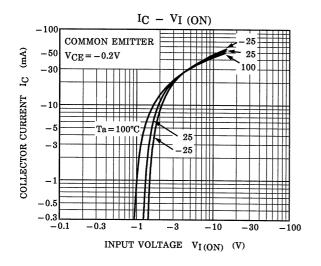
Q1

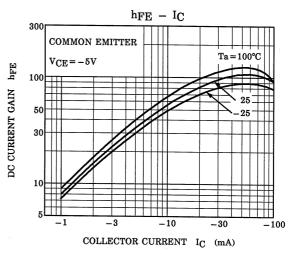


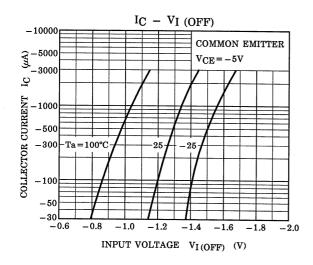




Q2







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